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Direct white light emission from inorganic-organic hybrid semiconductor bulk materials

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Supplementary Information

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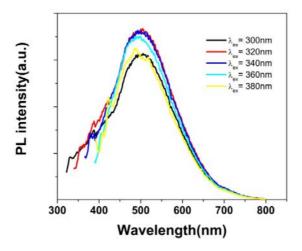


Fig. S1. Photoluminescence emission spectra taken at various excitation wavelength. The emission characteristics remain the same over the entire excitation wavelength range between 320 and 380 nm.

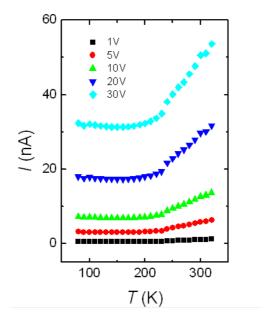


Fig. S2. I-V characteristics of a thin pellet of $[Cd_2Se_2(ba)]$:25mol% Te as a function of temperature.